



钜地半导体  
Tudi Semiconductor

## Product Specification

TUDI-MCP2551

High-Speed CAN Transceiver

网址 [www.sztdbdt.com](http://www.sztdbdt.com) Q

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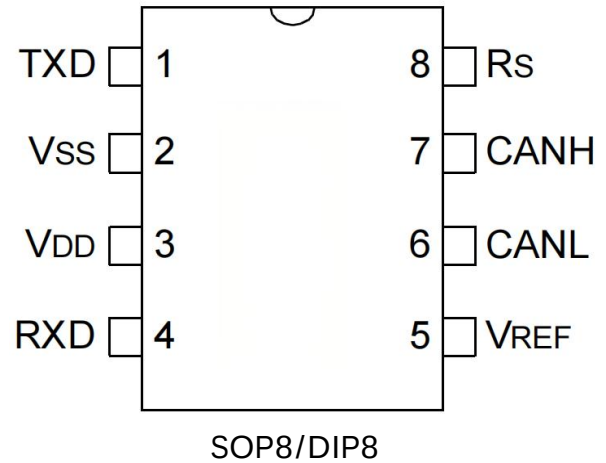
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## Features

- Supports 1 Mb/s operation
- Implements ISO-11898 standard physical layer requirements
- Suitable for 12V and 24V systems
- Externally-controlled slope for reduced RFI emissions
- Detection of ground fault (permanent Dominant) on TXD input
- Power-on Reset and voltage brown-out protection
- An unpowered node or brown-out event will not disturb the CAN bus
- Low current standby operation
- Protection against damage due to short-circuit conditions (positive or negative battery voltage)
- Protection against high-voltage transients
- Automatic thermal shutdown protection
- Up to 112 nodes can be connected
- High-noise immunity due to differential bus implementation
- Temperature ranges:
  - Industrial (I): -40°C to +85°C
  - Extended (E): -40°C to +125°C

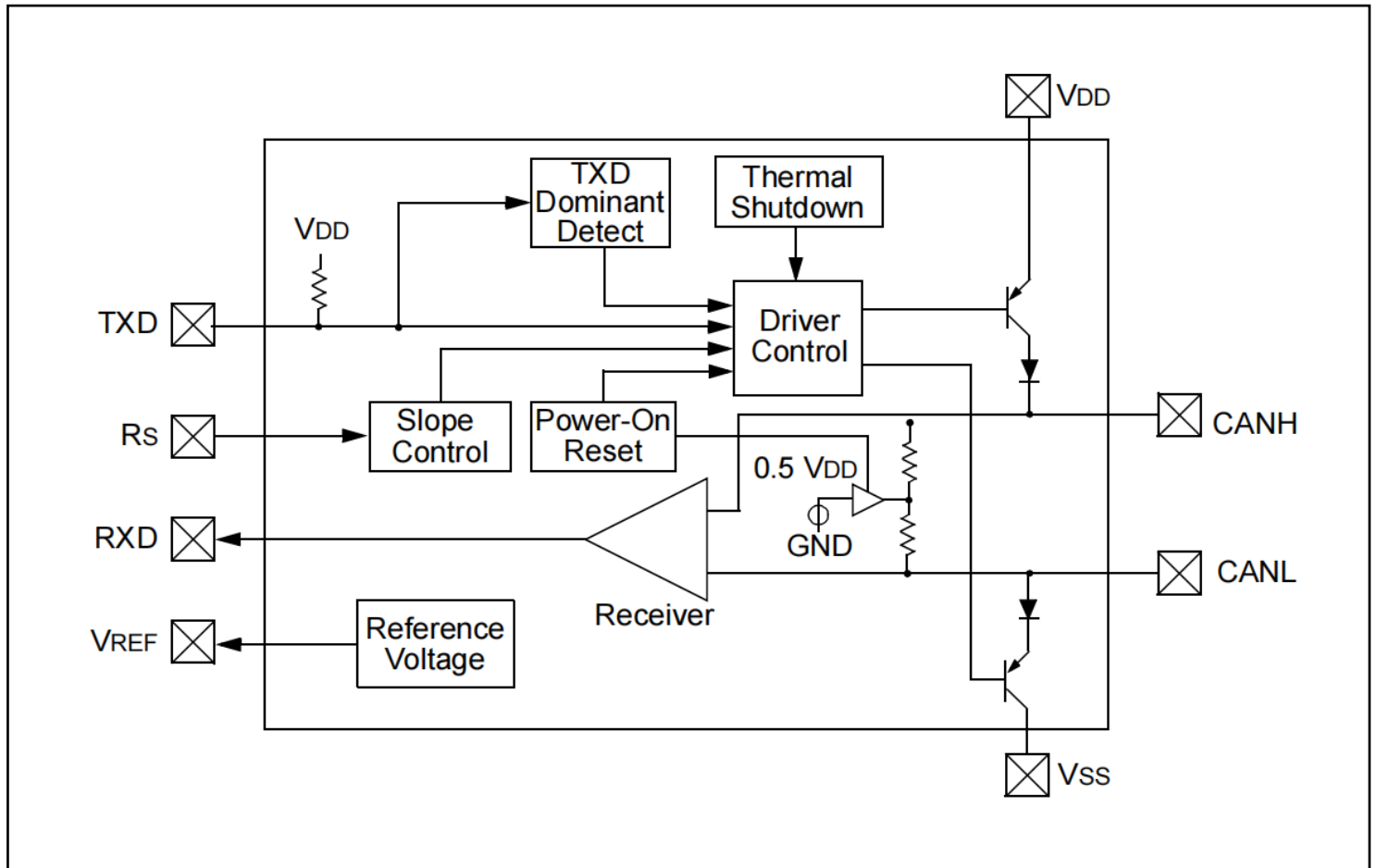


## Description

The MCP2551 is a high-speed CAN, fault-tolerant device that serves as the interface between a CAN protocol controller and the physical bus. The MCP2551 device provides differential transmit and receive capability for the CAN protocol controller, and is fully compatible with the ISO-11898 standard, including 24V requirements. It will operate at speeds of up to 1 Mb/s. Typically, each node in a CAN system must have a device to convert the digital signals generated by a CAN controller to signals suitable for transmission over the bus cabling (differential output). It also provides a buffer between the CAN controller and the high-voltage spikes that can be generated on the CAN bus by outside sources (EMI, ESD, electrical transients, etc.).



## Block Diagram



## Transmitter Function

The CAN bus has two states: Dominant and Recessive. A Dominant state occurs when the differential voltage between CANH and CANL is greater than a defined voltage (e.g., 1.2V). A Recessive state occurs when the differential voltage is less than a defined voltage (typically 0V). The Dominant and Recessive states correspond to the Low and High state of the TXD input pin, respectively. However, a Dominant state initiated by another CAN node will override a Recessive state on the CAN bus.

**MAXIMUM NUMBER OF NODES :** The MCP2551 CAN outputs will drive a minimum load of 45, allowing a maximum of 112 nodes to be connected (given a minimum differential input resistance of 20 k and a nominal termination resistor value of 120).



## Receiver Function

The RXD output pin reflects the differential bus voltage between CANH and CANL. The Low and High states of the RXD output pin correspond to the Dominant and Recessive states of the CAN bus, respectively.

## Internal Protection

CANH and CANL are protected against battery short-circuits and electrical transients that can occur on the CAN bus. This feature prevents destruction of the transmitter output stage during such a fault condition. The device is further protected from excessive current loading by thermal shutdown circuitry that disables the output drivers when the junction temperature exceeds a nominal limit of 165°C. All other parts of the chip remain operational, and the chip temperature is low-ered due to the decreased power dissipation in the transmitter outputs. This protection is essential to protect against bus line short-circuit-induced damage.

## Operating Modes

The RS pin allows three modes of operation to be selected:

- High-Speed
- Slope-Control
- Standby

These modes are summarized in Table 1 .

When in High-Speed or Slope-Control mode, the drivers for the CANH and CANL signals are internally regulated to provide controlled symmetry in order to minimize EMI emissions. Additionally, the slope of the signal transitions on CANH and CANL can be controlled with a resistor connected from pin 8 (RS) to ground. The slope must be proportional to the current output at RS, which will further reduce EMI emissions.

**HIGH-SPEED** : High-Speed mode is selected by connecting the  $R_s$  pin to  $V_{ss}$ . In this mode, the transmitter output drivers have fast output rise and fall times to support high-speed CAN bus rates.

**SLOPE-CONTROL** : Slope-Control mode further reduces EMI by limiting the rise and fall times of CANH and CANL. The slope, or slew rate (SR), is controlled by connecting an external resistor ( $R_{EXT}$ ) between RS and  $V_{OL}$  (usually ground). The slope is proportional to the current output at the RS pin. Since the current is primarily determined by the slope-control resistance value  $R_{EXT}$ , a certain slew rate is achieved by applying a specific resistance.

**STANDBY MODE** : The device may be placed in Standby or SLEEP mode by applying a high-level to the RS pin. In SLEEP mode, the transmitter is switched off and the receiver operates at a lower current. The receive pin on the controller side (RXD) is still functional, but will operate at a slower rate. The attached microcontroller can monitor RXD for CAN bus activity and place the transceiver into normal operation via the RS pin (at higher bus rates, the first CAN message may be lost).

**TABLE 1: MODES OF OPERATION**

| Mode          | Current at Rs Pin              | Resulting Voltage at Rs Pin        |
|---------------|--------------------------------|------------------------------------|
| Standby       | $-I_{RS} < 10\mu A$            | $V_{RS} > 0.75 V_{DD}$             |
| Slope-Control | $10\mu A < -I_{RS} < 200\mu A$ | $0.4 V_{DD} < V_{RS} < 0.6 V_{DD}$ |
| High-Speed    | $-I_{RS} < 610\mu A$           | $0 < V_{RS} < 0.3V_{DD}$           |

**TABLE 2: TRANSCEIVER TRUTH TABLE**

| $V_{DD}$                               | $V_{RS}$               | TXD           | CANH                   | CANL                   | Bus State <sup>(1)</sup> | RxD <sup>(1)</sup> |
|----------------------------------------|------------------------|---------------|------------------------|------------------------|--------------------------|--------------------|
| $4.5V \leq V_{DD} \leq 5.5V$           | $V_{RS} < 0.75 V_{DD}$ | 0             | HIGH                   | LOW                    | Dominant                 | 0                  |
|                                        |                        | 1 or floating | Not Driven             | Not Driven             | Recessive                | 1                  |
|                                        | $V_{RS} > 0.75 V_{DD}$ | X             | Not Driven             | Not Driven             | Recessive                | 1                  |
| $V_{POR} < V_{DD} < 4.5V$ (See Note 3) | $V_{RS} < 0.75 V_{DD}$ | 0             | HIGH                   | LOW                    | Dominant                 | 0                  |
|                                        |                        | 1 or floating | Not Driven             | Not Driven             | Recessive                | 1                  |
|                                        | $V_{RS} > 0.75 V_{DD}$ | X             | Not Driven             | Not Driven             | Recessive                | 1                  |
| $0 < V_{DD} < V_{POR}$                 | X                      | X             | Not Driven/<br>No Load | Not Driven/<br>No Load | High Impedance           | X                  |

Note 1: If another bus node is transmitting a Dominant bit on the CAN bus, then RXD is a logic '0'.

2: X = "don't care".

3: Device drivers will function, although outputs are not ensured to meet the ISO-11898 specification.

## TXD Permanent Dominant Detection

If the MCP2551 detects an extended Low state on the TXD input, it will disable the CANH and CANL output drivers in order to prevent the corruption of data on the CAN bus. The drivers are disabled if TXD is Low for more than 1.25 ms (minimum). This implies a maximum bit time of 62.5  $\mu$ s (16 kb/s bus rate), allowing up to 20 consecutive transmitted Dominant bits during a multiple bit error and error frame scenario. The drivers remain disabled as long as TXD remains Low. A rising edge on TXD will reset the timer logic and enable the CANH and CANL output drivers.

## Power-on Reset

When the device is powered on, CANH and CANL remain in a high-impedance state until  $V_{DD}$  reaches the voltage-level  $V_{PORH}$ . In addition, CANH and CANL will remain in a high-impedance state if TXD is Low when  $V_{DD}$  reaches  $V_{PORH}$ . CANH and CANL will become active only after TXD is asserted High. Once powered on, CANH and CANL will enter a high-impedance state if the voltage level at  $V_{DD}$  falls below  $V_{PORL}$ , providing voltage brown-out protection during normal operation.

## Pin Descriptions

The 8-pin pinout is listed in Table 3.

TABLE 3: MCP2551 PINOUT

| Pin Number | Pin Name  | Pin Function               |
|------------|-----------|----------------------------|
| 1          | TXD       | Transmit Data Input        |
| 2          | $V_{SS}$  | Ground                     |
| 3          | $V_{DD}$  | Supply Voltage             |
| 4          | RXD       | Receive Data Output        |
| 5          | $V_{REF}$ | Reference Output Voltage   |
| 6          | CANL      | CAN Low-Level Voltage I/O  |
| 7          | CANH      | CAN High-Level Voltage I/O |
| 8          | $R_s$     | Slope-Control Input        |



**TRANSMITTER DATA INPUT (TXD) :** TXD is a TTL-compatible input pin. The data on this pin is driven out on the CANH and CANL differential output pins. It is usually connected to the transmitter data output of the CAN controller device. When TXD is Low, CANH and CANL are in the Dominant state. When TXD is High, CANH and CANL are in the Recessive state, provided that another CAN node is not driving the CAN bus with a Dominant state. TXD has an internal pull-up resistor (nominal 25 k $\Omega$  to V<sub>DD</sub>).

**GROUND SUPPLY (VSS) :** Ground supply pin.

**SUPPLY VOLTAGE (VDD) :** Positive supply voltage pin.

**RECEIVER DATA OUTPUT (RXD) :** RXD is a CMOS-compatible output that drives High or Low depending on the differential signals on the CANH and CANL pins and is usually connected to the receiver data input of the CAN controller device. RXD is High when the CAN bus is Recessive and Low in the Dominant state.

**REFERENCE VOLTAGE (V<sub>REF</sub>) :** Reference Voltage Output (defined as V<sub>DD</sub>/2).

**CAN LOW (CANL) :** The CANL output drives the Low side of the CAN differential bus. This pin is also tied internally to the receive input comparator.

**CAN HIGH (CANH) :** The CANH output drives the high-side of the CAN differential bus. This pin is also tied internally to the receive input comparator.

**SLOPE RESISTOR INPUT (RS) :** The R<sub>s</sub> pin is used to select High-Speed, Slope-Control or Standby modes via an external biasing resistor.



## ELECTRICAL CHARACTERISTICS

### Terms and Definitions

A number of terms are defined in ISO-11898 that are used to describe the electrical characteristics of a CAN transceiver device. These terms and definitions are summarized in this section.

**BUS VOLTAGE :**  $V_{CANL}$  and  $V_{CANH}$  denote the voltages of the bus line wires CANL and CANH relative to ground of each individual CAN node.

**COMMON MODE BUS VOLTAGE RANGE :** Boundary voltage levels of  $V_{CANL}$  and  $V_{CANH}$  with respect to ground, for which proper operation will occur, if up to the maximum number of CAN nodes are connected to the bus.

**DIFFERENTIAL INTERNAL CAPACITANCE,  $C_{DIFF}$  (OF A CAN NODE)** Capacitance seen between CANL and CANH during the Recessive state when the CAN node is disconnected from the bus (see Figure 1).

**DIFFERENTIAL INTERNAL RESISTANCE,  $R_{DIFF}$  (OF A CAN NODE)** : Resistance seen between CANL and CANH during the Recessive state when the CAN node is disconnected from the bus (see Figure 1).

**DIFFERENTIAL VOLTAGE,  $V_{DIFF}$  (OF CAN BUS)** : Differential voltage of the two-wire CAN bus, value  $V_{DIFF} = V_{CANH} - V_{CANL}$ .

**INTERNAL CAPACITANCE,  $C_{IN}$  (OF A CAN NODE)** : Capacitance seen between CANL (or CANH) and ground during the Recessive state when the CAN node is disconnected from the bus (see Figure 1).

**INTERNAL RESISTANCE,  $R_{IN}$  (OF A CAN NODE)** : Resistance seen between CANL (or CANH) and ground during the Recessive state when the CAN node is disconnected from the bus (see Figure 1).

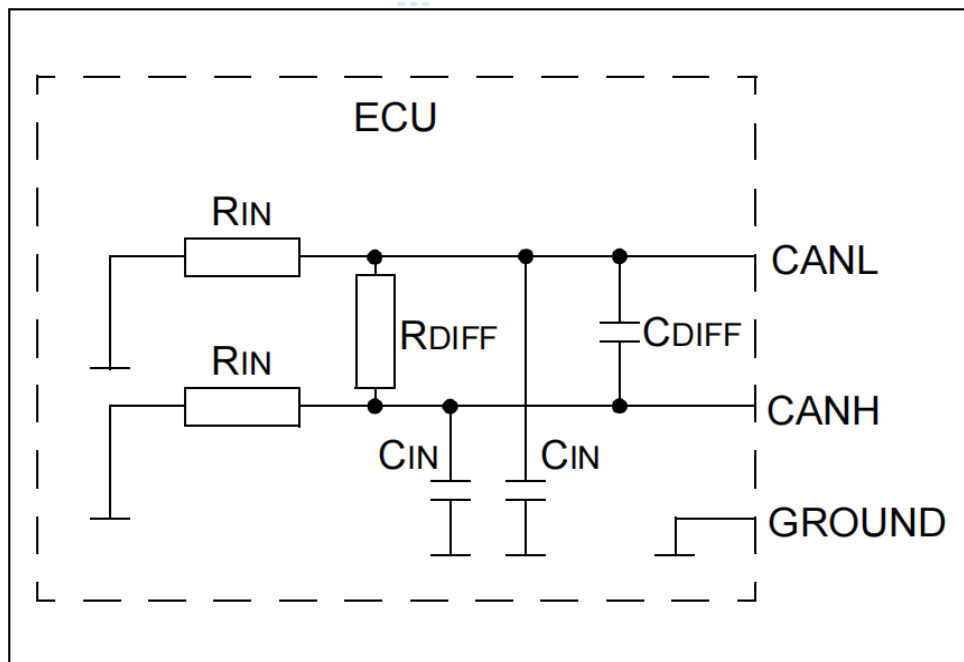


FIGURE 1: PHYSICAL LAYER DEFINITIONS



## Absolute Maximum Ratings

|                                                     |                                 |
|-----------------------------------------------------|---------------------------------|
| V <sub>DD</sub> .....                               | 7.0V                            |
| DC Voltage at TXD, RXD, VREF and VS.....            | -0.3V to V <sub>DD</sub> + 0.3V |
| DC Voltage at CANH, CANL (Note 1).....              | -42V to +42V                    |
| Transient Voltage on Pins 6 and 7 (Note 2) .....    | -250V to +250V                  |
| Storage temperature .....                           | -55°C to +150°C                 |
| Operating ambient temperature .....                 | -40°C to +125°C                 |
| Virtual Junction Temperature, TVJ (Note 3).....     | -40°C to +150°C                 |
| Soldering temperature of leads (10 seconds) .....   | +300°C                          |
| ESD protection on CANH and CANL pins (Note 4) ..... | 6 kV                            |
| ESD protection on all other pins (Note 4) .....     | 4 kV                            |

Note 1: Short-circuit applied when TXD is High and Low.

2: In accordance with ISO-7637.

3: In accordance with IEC 60747-1.

4: Classification A: Human Body Model.

NOTICE: Stresses above those listed under “ Maximum ratings ” may cause permanent damage to the device. This is a stress rating only and functional operation of the device at those or any other conditions above those indicated in the operational listings of this specification is not implied. Exposure to maximum rating conditions for extended periods may affect device reliability.

## DC Characteristics

| DC Specifications |                 |                | Electrical Characteristics:<br>Industrial (I): T <sub>AMB</sub> = -40°C to +85°C V <sub>DD</sub> = 4.5V to 5.5V<br>Extended (E): T <sub>AMB</sub> = -40°C to +125°C V <sub>DD</sub> = 4.5V to 5.5V |     |       |                                                  |
|-------------------|-----------------|----------------|----------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|-----|-------|--------------------------------------------------|
| Param No.         | Sym             | Characteristic | Min                                                                                                                                                                                                | Max | Units | Conditions                                       |
| Supply            |                 |                |                                                                                                                                                                                                    |     |       |                                                  |
| D1                | I <sub>DD</sub> | Supply Current | —                                                                                                                                                                                                  | 75  | mA    | Dominant;V <sub>TXD</sub> =0.8V;V <sub>DD</sub>  |
| D2                |                 |                | —                                                                                                                                                                                                  | 10  | mA    | Recessive;V <sub>TXD</sub> = +2V;Rs=47 kW        |
| D3                |                 |                | —                                                                                                                                                                                                  | 365 | μA    | -40°C≤T <sub>AMB</sub> ≤+85°C, Standby;(Note 2)  |
|                   |                 |                | —                                                                                                                                                                                                  | 465 | μA    | -40°C≤T <sub>AMB</sub> ≤+125°C, Standby;(Note 2) |

## DC Characteristics (Continued)

| Param No.                             | Sym                        | Characteristic                             | Min  | Max            | Units | Conditions                                                  |
|---------------------------------------|----------------------------|--------------------------------------------|------|----------------|-------|-------------------------------------------------------------|
| D4                                    | $V_{PORH}$                 | High-level of the Power-onReset comparator | 3.8  | 4.3            | V     | CANH,CANL outputs are activewhen $V_{DD} > V_{PORH}$        |
| D5                                    | $V_{PORL}$                 | Low-level of the Power-on Reset comparator | 3.4  | 4.0            | V     | CANH,CANL outputs are notactive when $V_{DD} < V_{PORL}$    |
| D6                                    | $V_{POD}$                  | Hysteresis of Power-on Reset comparator    | 0.3  | 0.8            | V     | Note 1                                                      |
| <b>Bus Line(CANH;CANL)Transmitter</b> |                            |                                            |      |                |       |                                                             |
| D7                                    | $V_{CANH(r)}; V_{CANL(r)}$ | CANH,CANL Recessive bus voltage            | 2.0  | 3.0            | V     | $V_{TXD} = V_{DD}$ ;no load.                                |
| D8                                    | $I_{O(CANH)(reces)}$       | Recessive output current                   | -2   | +2             | mA    | $-2V < V(CAHL,CANH) < +7V$ ,<br>$0V < V_{DD} < 5.5V$        |
| D9                                    | $I_{O(CANL)(reces)}$       |                                            | -10  | +10            | mA    | $-5V < V(CANL,CANH) < +40V$ ,<br>$0V < V_{DD} < 5.5V$       |
| D10                                   | $V_{O(CANH)}$              | CANH Dominant output voltage               | 2.75 | 4.5            | V     | $V_{TXD} = 0.8V$                                            |
| D11                                   | $V_{O(CANL)}$              | CANL Dominant output voltage               | 0.5  | 2.25           | V     | $V_{TXD} = 0.8V$                                            |
| D12                                   | $V_{DIFF(r)(o)}$           | Recessive differential output voltage      | -500 | +50            | mV    | $V_{TXD} = 2V$ ;no load                                     |
| D13                                   | $V_{DIFF(d)(o)}$           | Dominant differential output voltage       | 1.5  | 3.0            | V     | $V_{TXD} = 0.8V; V_{DD} = 5V$<br>$40W < R_L < 60W$ (Note 2) |
| D14                                   | $I_{O(SC)(CANH)}$          | CANH short-circuit output current          | —    | -200           | mA    | $V_{CANH} = -5V$                                            |
| D15                                   |                            |                                            | —    | -100 (typical) | mA    | $V_{CANH} = -40V, +40V$ .(Note 1)                           |
| D16                                   | $I_{O(SC)(CANL)}$          | CANL short-circuit output current          | —    | 200            | mA    | $V_{CANL} = -40V, +40V$ .(Note 1)                           |
| D17                                   | $V_{DIFF(r)(i)}$           | Recessive differential input voltage       | -1.0 | +0.5           | V     | $-2V < V(CANL,CANH) < +7V$<br>(Note 3)                      |
|                                       |                            |                                            | -1.0 | +0.4           | V     | $-12V < V(CANL,CANH) < +12V$<br>(Note 3)                    |



## DC Characteristics (Continued)

| Param No.                                                                   | Sym              | Characteristic                                               | Min              | Max              | Units      | Conditions                                    |
|-----------------------------------------------------------------------------|------------------|--------------------------------------------------------------|------------------|------------------|------------|-----------------------------------------------|
| <b>Bus Line(CANH;CANL)Receiver:[TXD=2V;pins 6 and 7 externally driven]</b>  |                  |                                                              |                  |                  |            |                                               |
| D18                                                                         | $V_{DIFF(d)(i)}$ | Dominant differential input voltage                          | 0.9              | 5.0              | V          | $-2V < V_{(CANL,CANH)} < +7V$<br>(Note 3)     |
|                                                                             |                  |                                                              | 1.0              | 5.0              | V          | $-12V < V_{(CANL,CANH)} < +12V$ (Note 3)      |
| D19                                                                         | $V_{DIFF(h)(i)}$ | Differential input hysteresis                                | 100              | 200              | mV         | See Figure 4(Note 1)                          |
| D20                                                                         | $R_{IN}$         | CANH,CANL Common-mode input resistance                       | 5                | 50               | k $\Omega$ |                                               |
| D21                                                                         | $R_{IN(d)}$      | Deviation between CANH and CANL Common-mode input resistance | -3               | +3               | %          | $V_{CANH} = V_{CANL}$                         |
| <b>Bus Line (CANH;CANL)Receiver:[TXD=2V;pins 6 and 7 externally driven]</b> |                  |                                                              |                  |                  |            |                                               |
| D22                                                                         | $R_{DIFF}$       | Differential input resistance                                | 20               | 100              | k $\Omega$ |                                               |
| D24                                                                         | $I_{LI}$         | CANH,CANL input leakage current                              | —                | 150              | $\mu A$    | $V_{DD} < V_{POR}, V_{CANH} = V_{CANL} = +5V$ |
| <b>Transmitter Data Input (TXD)</b>                                         |                  |                                                              |                  |                  |            |                                               |
| D25                                                                         | $V_{IH}$         | High-level input voltage                                     | 2.0              | $V_{DD}$         | V          | Output Recessive                              |
| D26                                                                         | $V_{IL}$         | Low-level input voltage                                      | $V_{SS}$         | +0.8             | V          | Output Dominant                               |
| D27                                                                         | $I_{IH}$         | High-level input current                                     | -1               | +1               | $\mu A$    | $V_{TXD} = V_{DD}$                            |
| D28                                                                         | $I_{IL}$         | Low-level input current                                      | -100             | -400             | $\mu A$    | $V_{TXD} = 0V$                                |
| <b>Receiver Data Output (RXD)</b>                                           |                  |                                                              |                  |                  |            |                                               |
| D31                                                                         | $V_{OH}$         | High-level output voltage                                    | 0.7<br>$V_{DD}$  | —                | V          | $I_{OH} = 8mA$                                |
| D32                                                                         | $V_{OL}$         | Low-level output voltage                                     | —                | 0.8              | V          | $I_{OL} = 8mA$                                |
| <b>Voltage Reference Output (VREF)</b>                                      |                  |                                                              |                  |                  |            |                                               |
| D33                                                                         | $V_{REF}$        | Reference output voltage                                     | 0.45<br>$V_{DD}$ | 0.55<br>$V_{DD}$ | V          | $-50 \mu A < I_{VREF} < 50 \mu A$             |



## DC Characteristics (Continued)

| Param No.                     | Sym         | Characteristic                  | Min                 | Max                 | Units | Conditions                                      |
|-------------------------------|-------------|---------------------------------|---------------------|---------------------|-------|-------------------------------------------------|
| Standby/Slope-Control(Rs pin) |             |                                 |                     |                     |       |                                                 |
| D34                           | $V_{STB}$   | Input voltage for standby mode  | 0.75V <sub>DD</sub> | —                   | V     |                                                 |
| D35                           | $I_{SLOPE}$ | Slope-control mode current      | -10                 | -200                | μA    |                                                 |
| D36                           | $V_{SLOPE}$ | Slope-control mode voltage      | 0.4 V <sub>DD</sub> | 0.6 V <sub>DD</sub> | V     |                                                 |
| Thermal Shutdown              |             |                                 |                     |                     |       |                                                 |
| D37                           | $T_{J(sd)}$ | Shutdown junction temperature   | 155                 | 180                 | °C    | Note 1                                          |
| D38                           | $T_{J(n)}$  | Shutdown temperature hysteresis | 20                  | 30                  | °C    | -12V < V <sub>(CANL,CANH)</sub> < +12V (Note 3) |

Note 1: This parameter is periodically sampled and not 100% tested.

2. I<sub>TXD</sub> = I<sub>RXD</sub> = I<sub>VREF</sub> = 0 mA; 0V < V<sub>CANL</sub> < V<sub>DD</sub>; 0V < V<sub>CANH</sub> < V<sub>DD</sub>; V<sub>RS</sub> = V<sub>DD</sub>

3: This is valid for the receiver in all modes; High-speed, Slope-control and Standby

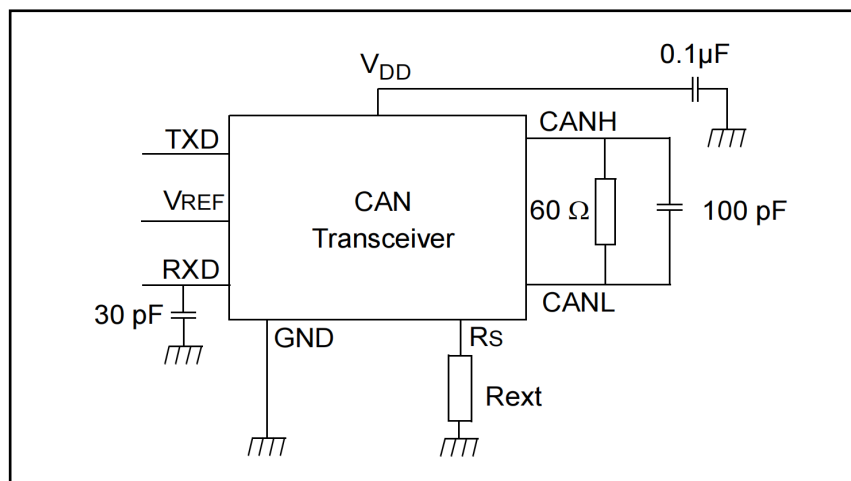


FIGURE 2: TEST CIRCUIT FOR ELECTRICAL CHARACTERISTICS

Note: RS may be connected to V<sub>DD</sub> or GND via a load resistor depending on desired operating mode as described in “Supply Voltage (V<sub>DD</sub>)”.

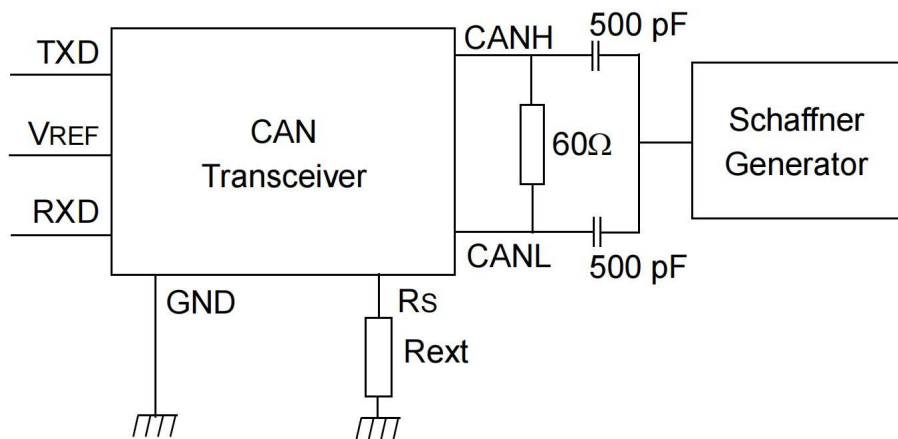


FIGURE 3: TEST CIRCUIT FOR AUTOMOTIVE TRANSIENTS

Note: RS may be connected to  $V_{DD}$  or GND via a load resistor depending on desired operating mode as described in “ Slope Resistor Input (Rs) ”.

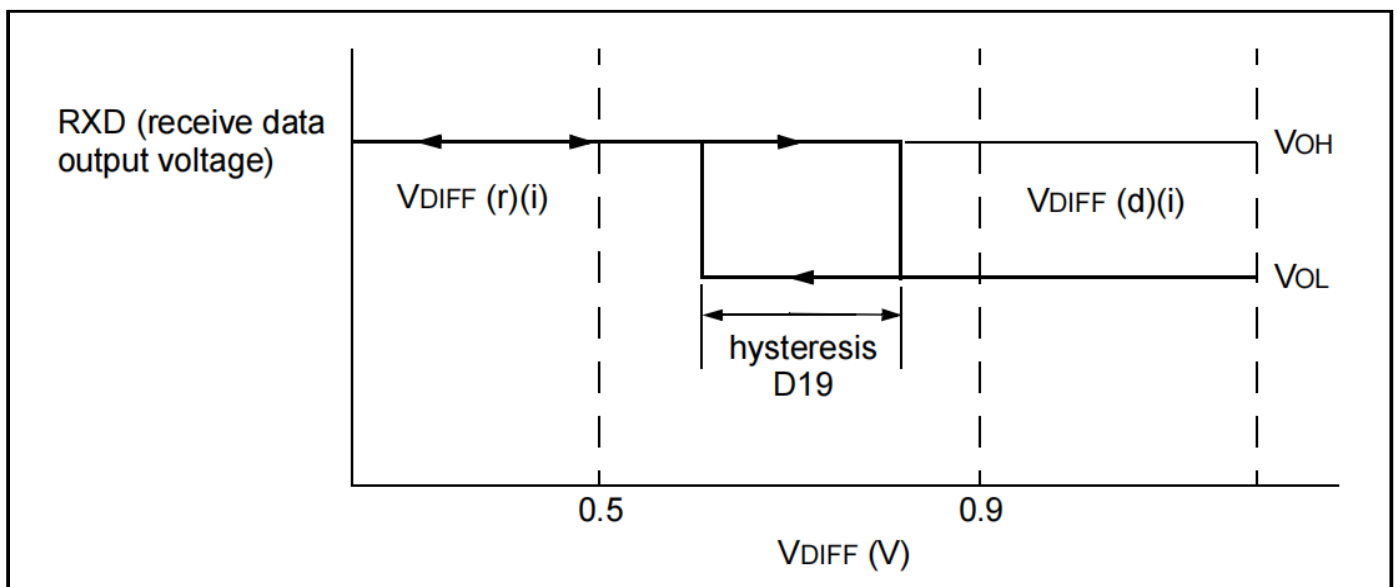


FIGURE 4: HYSTERESIS OF THE RECEIVER



## AC Characteristics

| AC Specifications |                        |                                        | Electrical Characteristics:<br>Industrial (I): $T_{AMB} = -40^{\circ}\text{C}$ to $+85^{\circ}\text{C}$ $V_{DD} = 4.5\text{V}$ to $5.5\text{V}$<br>Extended (E): $T_{AMB} = -40^{\circ}\text{C}$ to $+125^{\circ}\text{C}$ $V_{DD} = 4.5\text{V}$ to $5.5\text{V}$ |              |                       |                                                                                             |
|-------------------|------------------------|----------------------------------------|--------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|--------------|-----------------------|---------------------------------------------------------------------------------------------|
| Param No.         | Sym                    | Characteristic                         | Min                                                                                                                                                                                                                                                                | Max          | Units                 | Conditions                                                                                  |
| 1                 | $t_{BIT}$              | Bit time                               | 1                                                                                                                                                                                                                                                                  | 62.5         | $\mu\text{S}$         | $V_{RS}=0\text{V}$                                                                          |
| 2                 | $f_{BIT}$              | Bit frequency                          | 16                                                                                                                                                                                                                                                                 | 1000         | kHz                   | $V_{RS}=0\text{V}$                                                                          |
| 3                 | TtxL2bus(d)            | Delay TXD to bus active                | —                                                                                                                                                                                                                                                                  | 70           | ns                    | $-40^{\circ}\text{C} \leq T_{AMB} \leq +125^{\circ}\text{C}$ ,<br>$V_{RS}=0\text{V}$        |
| 4                 | TtxH2bus(r)            | Delay TXD to bus inactive              | —                                                                                                                                                                                                                                                                  | 125          | ns                    | $-40^{\circ}\text{C} \leq T_{AMB} \leq +85^{\circ}\text{C}$ ,<br>$V_{RS}=0\text{V}$         |
|                   |                        |                                        | —                                                                                                                                                                                                                                                                  | 170          | ns                    | $-40^{\circ}\text{C} \leq T_{AMB} \leq +125^{\circ}\text{C}$ ,<br>$V_{RS}=0\text{V}$        |
| 5                 | TtxL2rx(d)             | Delay TXD to receive active            | —                                                                                                                                                                                                                                                                  | 130          | ns                    | $-40^{\circ}\text{C} \leq T_{AMB} \leq +125^{\circ}\text{C}$ ,<br>$V_{RS}=0\text{V}$        |
|                   |                        |                                        | —                                                                                                                                                                                                                                                                  | 250          | ns                    | $-40^{\circ}\text{C} \leq T_{AMB} \leq +125^{\circ}\text{C}$ ,<br>$V_{RS}=47\text{k}\Omega$ |
| 6                 | TtxH2rx(r)             | Delay TXD to receiver inactive         | —                                                                                                                                                                                                                                                                  | 175          | ns                    | $-40^{\circ}\text{C} \leq T_{AMB} \leq +85^{\circ}\text{C}$ ,<br>$V_{RS}=0\text{V}$         |
|                   |                        |                                        | —                                                                                                                                                                                                                                                                  | 225          | ns                    | $-40^{\circ}\text{C} \leq T_{AMB} \leq +85^{\circ}\text{C}$ ,<br>$V_{RS}=47\text{k}\Omega$  |
|                   |                        |                                        | —                                                                                                                                                                                                                                                                  | 235          | ns                    | $-40^{\circ}\text{C} \leq T_{AMB} \leq +125^{\circ}\text{C}$ ,<br>$V_{RS}=0\text{V}$        |
|                   |                        |                                        | —                                                                                                                                                                                                                                                                  | 400          | ns                    | $-40^{\circ}\text{C} \leq T_{AMB} \leq +125^{\circ}\text{C}$ ,<br>$V_{RS}=47\text{k}\Omega$ |
| 7                 | SR                     | CANH,CANL slew rate                    | 5.5                                                                                                                                                                                                                                                                | 8.5          | $\text{V}\mu\text{s}$ | Refer to Figure 2;<br>$V_{RS}=47\text{k}\Omega$ , (Note 1)                                  |
| 10                | $t_{WAKE}$             | Wake-up time from standby(Rs pin)      | —                                                                                                                                                                                                                                                                  | 5            | $\mu\text{s}$         | See Figure 6                                                                                |
| 11                | TbusD2rx(s)            | Bus Dominant to RXD Low (Standby mode) | —                                                                                                                                                                                                                                                                  | 550          | ns                    | $V_{RS}=+4\text{V}$ ; (See Figure 7)                                                        |
| 12                | CIN(CANH)<br>CIN(CANL) | CANH;CANL input capacitance            | —                                                                                                                                                                                                                                                                  | 20 (typical) | pF                    | 1 Mb/s data rate; $V_{TXD}=V_{DD}$ , (Note 1)                                               |



## AC Characteristics(Continued)

| AC Specifications |                   |                                          | Electrical Characteristics:<br>Industrial (I): T <sub>AMB</sub> = -40°C to +85°C V <sub>DD</sub> = 4.5V to 5.5V<br>Extended (E): T <sub>AMB</sub> = -40°C to +125°C V <sub>DD</sub> = 4.5V to 5.5V |              |       |                                                                |
|-------------------|-------------------|------------------------------------------|----------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|--------------|-------|----------------------------------------------------------------|
| Param No.         | Sym               | Characteristic                           | Min                                                                                                                                                                                                | Max          | Units | Conditions                                                     |
| 13                | C <sub>DIFF</sub> | Differential input capacitance           | —                                                                                                                                                                                                  | 10 (typical) | pF    | 1 Mb/s data rate (Note 1)                                      |
| 14                | TtxL2busZ         | TX Permanent Dominant Timer Disable Time | 1.25                                                                                                                                                                                               | 4            | ms    |                                                                |
| 15                | TtxR2pdt(res)     | TX Permanent Dominant Timer Reset Time   | —                                                                                                                                                                                                  | 1            | μs    | Rising edge on TXD while device is in permanent Dominant state |

Note 1: This parameter is periodically sampled and not 100% tested.

## Timing Diagrams and Specifications

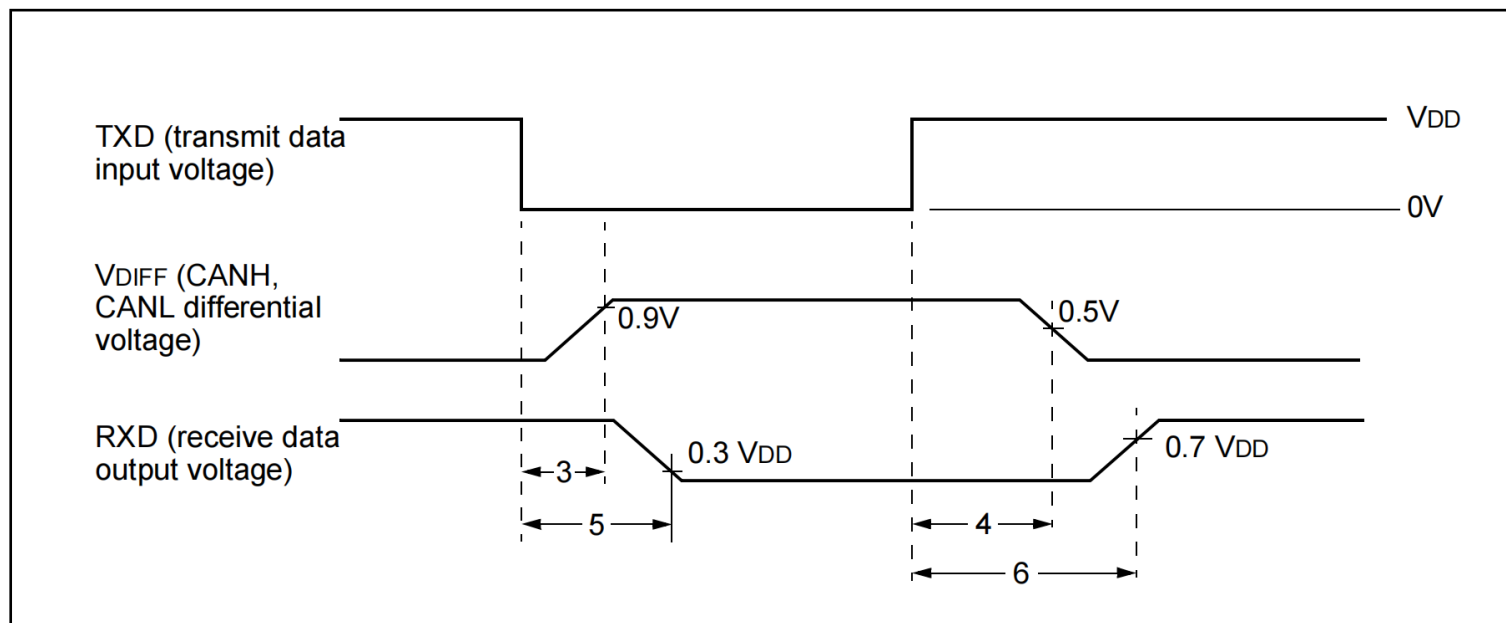


FIGURE 5: TIMING DIAGRAM FOR AC CHARACTERISTICS

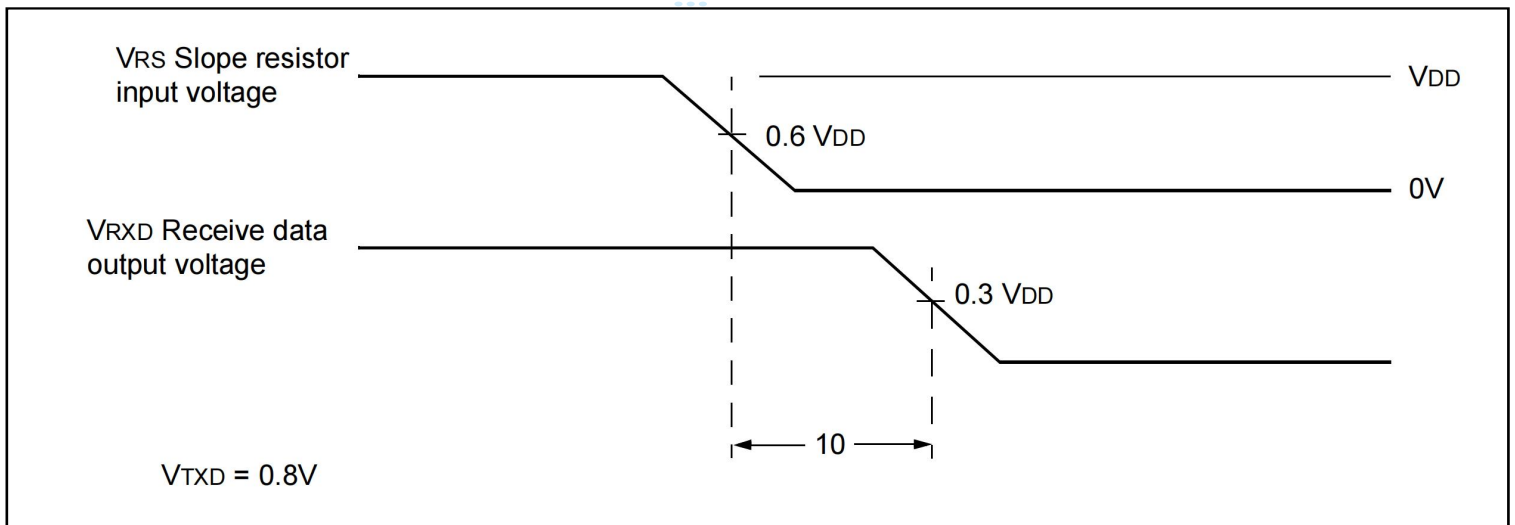


FIGURE 6: TIMING DIAGRAM FOR WAKE-UP FROM STANDBY

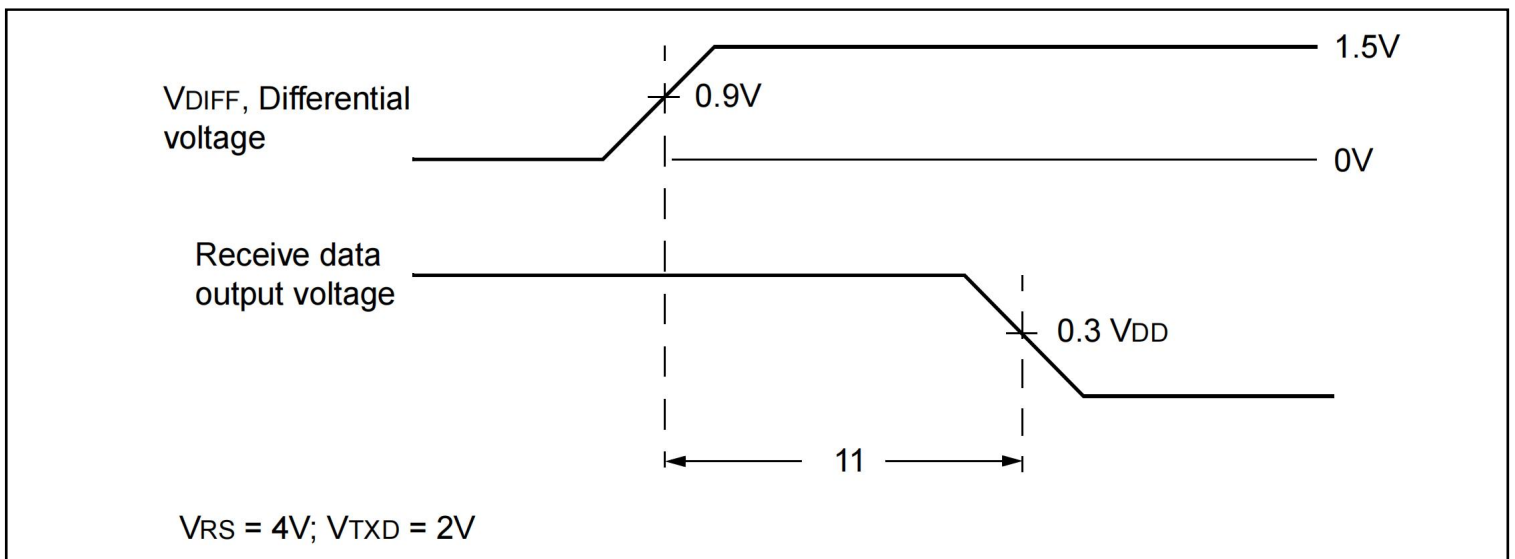


FIGURE 7: TIMING DIAGRAM FOR BUS DOMINANT TO RXD LOW (STANDBY MODE)

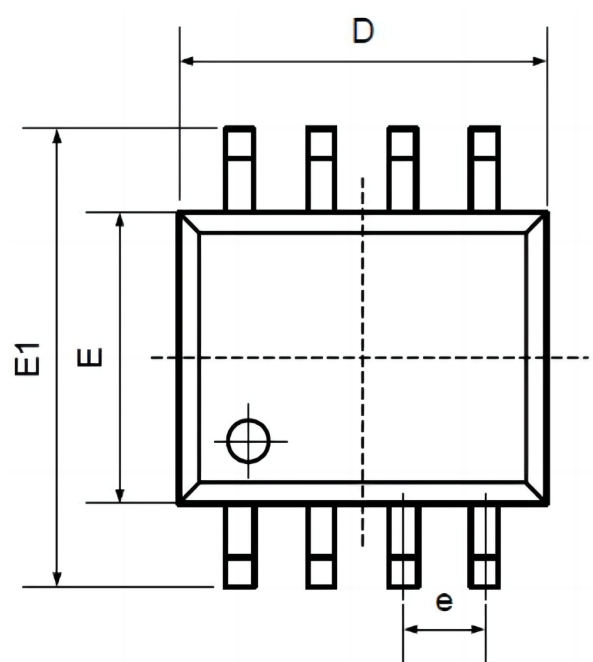
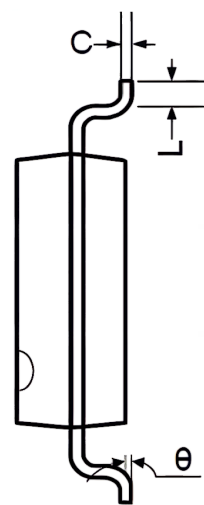
## Order information

| Order Number       | Package | Package Quantity      | Marking<br>On The park | Temperature     |
|--------------------|---------|-----------------------|------------------------|-----------------|
| MCP2551T-I/SN-TUDI | SOP8    | Tape,Reel,4000        | 2551-I/SN              | -40°C to +85°C  |
|                    |         |                       | MCP2551I/SN            |                 |
| MCP2551T-E/SN-TUDI | SOP8    | Tape,Reel,4000        | 2551-E/SN              | -40°C to +125°C |
|                    |         |                       | MCP2551ESN             |                 |
| MCP2551-I/P-TUDI   | DIP8    | Tube,50,A box of 2000 | 2551-I/P               | -40°C to +85°C  |
|                    |         |                       | MCP2551-I/P            |                 |
| MCP2551-E/P-TUDI   | DIP8    | Tube,50,A box of 2000 | 2551-E/P               | -40°C to +125°C |
|                    |         |                       | MCP2551-E/P            |                 |

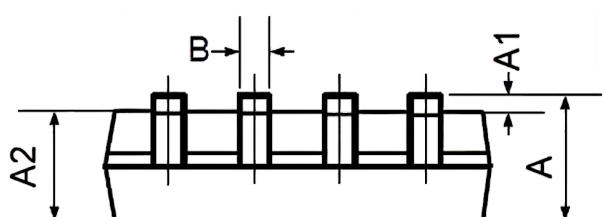
## Revision history

|      | Date   | Revision                      | Page |
|------|--------|-------------------------------|------|
| V1.0 | 2020/6 | New                           | 1-9  |
| V1.1 | 2024/2 | Update model and PDF template | 1-21 |

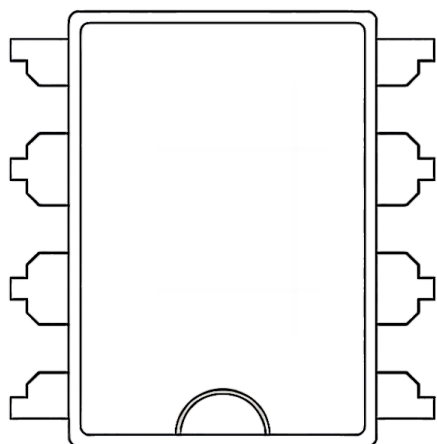
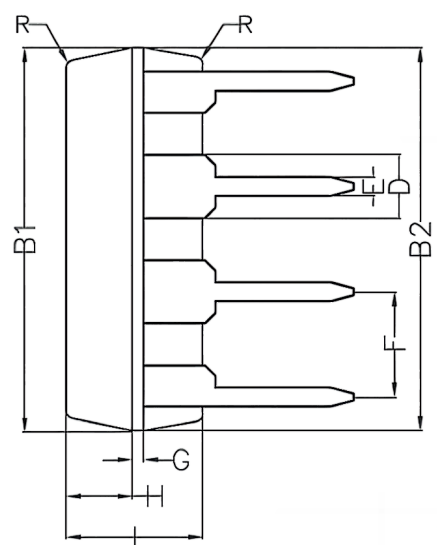
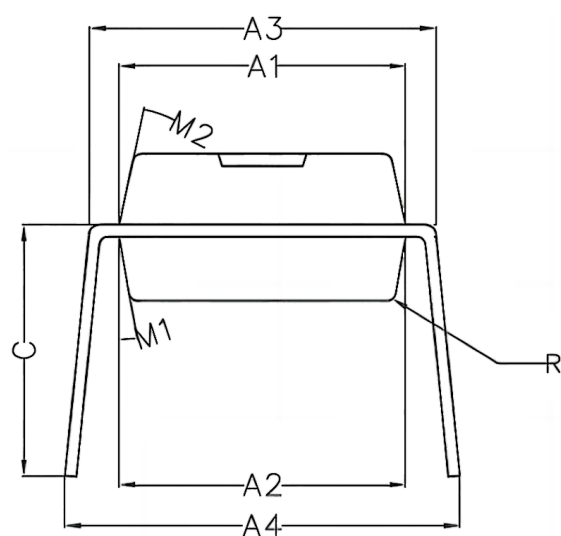
## Package SOP8



| Symbol | Dimensions<br>In Millimeters |       | Dimensions<br>In Inches |       |
|--------|------------------------------|-------|-------------------------|-------|
|        | Min                          | Max   | Min                     | Max   |
| A      | 1.350                        | 1.750 | 0.053                   | 0.069 |
| A1     | 0.100                        | 0.250 | 0.004                   | 0.010 |
| A2     | 1.350                        | 1.550 | 0.053                   | 0.061 |
| B      | 0.330                        | 0.510 | 0.013                   | 0.020 |
| C      | 0.190                        | 0.250 | 0.007                   | 0.010 |
| D      | 4.780                        | 5.000 | 0.188                   | 0.197 |
| E      | 3.800                        | 4.000 | 0.150                   | 0.157 |
| E1     | 5.800                        | 6.300 | 0.228                   | 0.248 |
| e      | 1.270TYP                     |       | 0.050TYP                |       |
| L      | 0.400                        | 1.270 | 0.016                   | 0.050 |
| θ      | 0°                           | 8°    | 0°                      | 8°    |



## Package DIP8



| Symbol | Min  | Non  | Max  |
|--------|------|------|------|
| A1     | 6.28 | 6.33 | 6.38 |
| A2     | 6.33 | 6.38 | 6.43 |
| A3     | 7.52 | 7.62 | 7.72 |
| A4     | 7.80 | 8.40 | 9.00 |
| B1     | 9.15 | 9.20 | 9.25 |
| B2     | 9.20 | 9.25 | 9.30 |
| C      |      | 5.57 |      |
| D      |      | 1.52 |      |
| E      | 0.43 | 0.45 | 0.47 |
| F      |      | 2.54 |      |
| G      |      | 0.25 |      |
| H      | 1.54 | 1.59 | 1.64 |
| I      | 3.22 | 3.27 | 3.32 |
| R      |      | 0.20 |      |
| M1     | 9°   | 10°  | 11°  |
| M2     | 11°  | 12°  | 13°  |



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